VS-MBRD320-M3, VS-MBRD330-M3, VS-MBRD340-M3

Vishay Semiconductors

High Performance Schottky Rectifier, 3.0 A



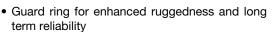
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SHAY

PRIMARY CHARACTERISTICS							
I _{F(AV)}	3.0 A						
V _R	20 V, 30 V, 40 V						
V _F at I _F	0.49 V						
I _{RM}	20 mA at 125 °C						
T _J max.	150 °C						
E _{AS}	8 mJ						
Package	DPAK (TO-252AA)						
Circuit configuration	Single						

FEATURES

• Low forward voltage drop



- Popular DPAK outline
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-MBRD320-M3, VS-MBRD330-M3, VS-MBRD340-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES I						
I _{F(AV)}	Rectangular waveform	3.0	А					
V _{RRM}		20 to 40	V					
I _{FSM}	t _p = 5 μs sine	490	А					
V _F	3 A _{pk} , T _J = 125 °C	0.49	V					
TJ		-40 to +150	°C					

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-MBRD320-M3	VS-MBRD330-M3	VS-MBRD340-M3	UNITS			
Maximum DC reverse voltage	V _R	20	30	40	V			
Aaximum working peak reverse voltage V _{RWM}		20	30	40	v			

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS			
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T_L = 133 °C, re	3.0					
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	490	А			
	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	75				
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 16 mH	8.0	mJ				
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1.0	А			

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CC	NDITIONS	TYP.	MAX.	UNITS		
Maximum forward voltage drop See fig. 1		3 A	T _{.1} = 25 °C	0.48	0.6	v		
	V _{FM} ⁽¹⁾	6 A	1j=25 0	0.58	0.7			
		3 A	T.I = 125 °C	0.41	0.49			
		6 A	$1_{\rm J} = 125$ C	0.55	0.625			
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B} = \text{Rated } V_{\rm B}$	0.02	0.2			
See fig. 2		T _J = 125 °C	$v_{\rm R} = Raled v_{\rm R}$	10.7	20	mA		
Typical junction capacitance	CT	V _R = 5 V _{DC} (test signal ran	189	-	pF			
Typical series inductance	L _S	Measured lead to lead 5 n	5.0	-	nH			
Maximum voltage rate of change	dV/dt	Rated V _R	-	10 000	V/µs			

Note

 $^{(1)}\,$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction temperature range	T _J ⁽¹⁾		-40 to +150	°C			
Maximum storage temperature range	T _{Stg}		-40 to +175	U			
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	6.0	°C/W			
Maximum thermal resistance, junction to ambient	R _{thJA}		80	0/14			
Approximate weight			0.3	g			
Approximate weight			0.01	oz.			
			MBRD320				
Marking device		Case style DPAK (TO-252AA)	MBRD330				
			MBR	D340			

Note

(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

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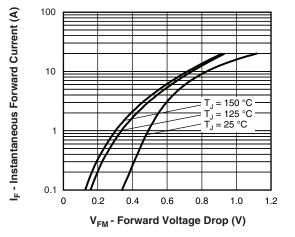


Fig. 1 - Maximum Forward Voltage Drop Characteristics

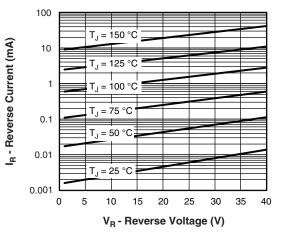


Fig. 2 - Typical Values of Reverse Current vs. **Reverse Voltage**

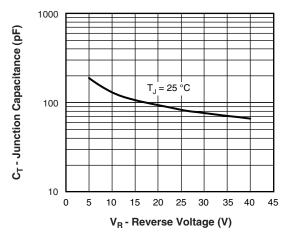
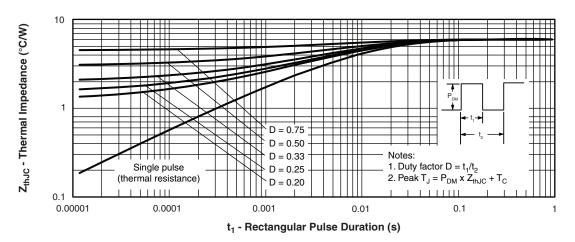
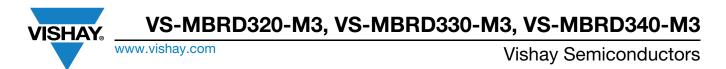
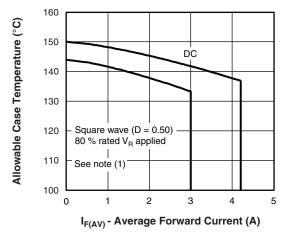


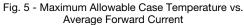
Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

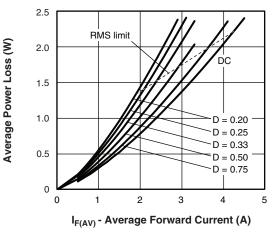














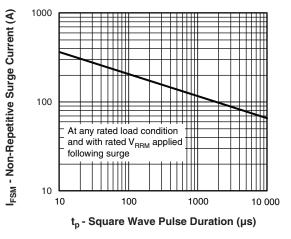


Fig. 7 - Maximum Non-Repetitive Surge Current

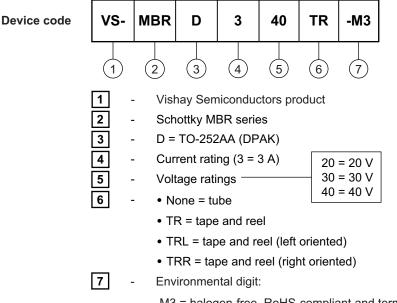
Note

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ORDERING INFORMATION TABLE



-M3 = halogen-free, RoHS-compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-MBRD320-M3	75	3000	Antistatic plastic tube						
VS-MBRD320TR-M3	2000	2000	13" diameter reel						
VS-MBRD320TRL-M3	3000	3000	13" diameter reel						
VS-MBRD320TRR-M3	3000	3000	13" diameter reel						
VS-MBRD330-M3	75	3000	Antistatic plastic tube						
VS-MBRD330TR-M3	2000	2000	13" diameter reel						
VS-MBRD330TRL-M3	3000	3000	13" diameter reel						
VS-MBRD330TRR-M3	3000	3000	13" diameter reel						
VS-MBRD340-M3	75	3000	Antistatic plastic tube						
VS-MBRD340TR-M3	2000	2000	13" diameter reel						
VS-MBRD340TRL-M3	3000	3000	13" diameter reel						
VS-MBRD340TRR-M3	3000	3000	13" diameter reel						

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95627					
Part marking information	www.vishay.com/doc?95176					
Packaging information	www.vishay.com/doc?95033					





D-PAK (TO-252AA) "M"

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	HES NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC		
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410		
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070		
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.		
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC		
С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3	
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040		
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2	
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°		
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°		
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°		

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁶⁾ Dimension b1 and c1 applied to base metal only

⁽⁷⁾ Datum A and B to be determined at datum plane H

⁽⁸⁾ Outline conforms to JEDEC[®] outline TO-252AA



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